TOSHIBA Transistor Silicon PNP Triple Diffused Type

2SA1941

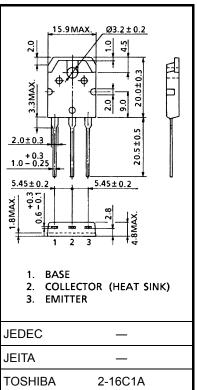
Power Amplifier Applications

• High breakdown voltage: V_{CEO} = -140 V (min)

- Complementary to 2SC5198
- Recommended for 70-W high-fidelity audio frequency amplifier output stage.

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-140	V
Collector-emitter voltage	V _{CEO}	-140	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ι _C	-10	А
Base current	Ι _Β	-1	А
Collector power dissipation (Tc = 25°C)	P _C	100	W
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	−55 to 150	°C

Absolute Maximum Ratings (Tc = 25°C)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

Weight: 4.7 g (typ.)

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

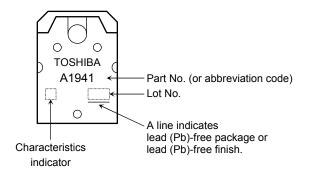
Unit: mm

Electrical Characteristics (Tc = 25°C)

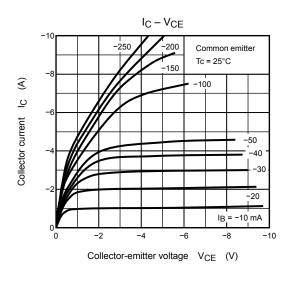
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -140 \text{ V}, I_{E} = 0$	_	_	-5.0	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -5 V, I _C = 0	_	_	-5.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	$I_{\rm C}$ = -50 mA, $I_{\rm B}$ = 0	-140	_	_	V
DC current gain	h _{FE (1)} (Note)	V _{CE} = -5 V, I _C = -1 A	55		160	
	h _{FE (2)}	V _{CE} = -5 V, I _C = -5 A	35	83	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = -7 A, I _B = -0.7 A	_	-0.8	-2.0	V
Base-emitter voltage	V _{BE}	V _{CE} = -5 V, I _C = -5 A	_	-1.0	-1.5	V
Transition frequency	f _T	V _{CE} = -5 V, I _C = -1 A	_	30	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	320	_	pF

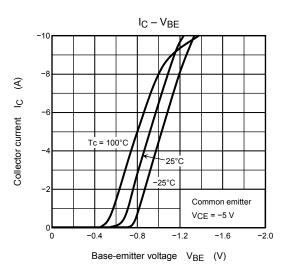
Note: h_{FE (1)} classification R: 55 to 110, O: 80 to 160

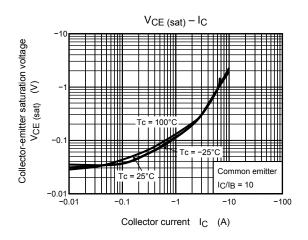
Marking

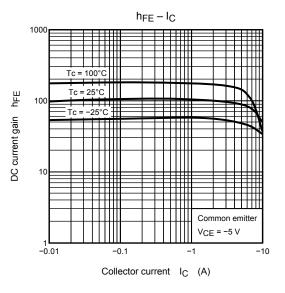


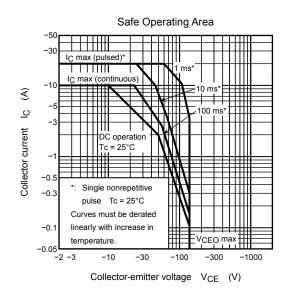
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